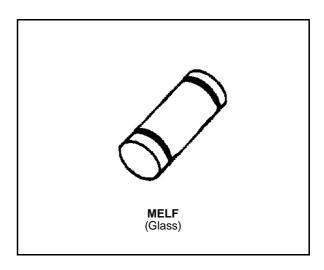


TMBYV 10-60

SMALL SIGNAL SCHOTTKY DIODE

DESCRIPTION

Metal to silicon rectifier diode in glass case featuring very low forward voltage drop and fast recovery time, intended for low voltage switching mode power supply, polarity protection and high frequency circuits.



ABSOLUTE MAXIMUM RATINGS (limiting values)

Symbol	Parameter	Value	Unit	
V_{RRM}	Repetitive Peak Reverse Voltage	Peak Reverse Voltage		
I _{F (AV)}	Average Forward Current	1	Α	
I _{FSM}	Surge non Repetitive Forward Current	$T_i = 25 ^{\circ}\text{C}$ $t_p = 10\text{ms}$	20 Sinusoidal Pulse	Α
		$T_i = 25 ^{\circ}\text{C}$ $t_p = 300 \mu\text{s}$	40 Rectangular Pulse	
T _{stg} T _j	Storage and Junction Temperature Range		- 65 to + 150 - 65 to + 125	°C °C
T _L	Maximum Lead Temperature for Soldering during	260	°C	

THERMAL RESISTANCE

Symbol	Parameter	Value	Unit
R _{th (j - l)}	Junction-leads	110	°C/W

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ELECTRICAL CHARACTERISTICS

STATIC CHARACTERISTICS

Symbol	Test Conditions			Тур.	Max.	Unit
I _R *	T _j = 25°C	$V_R = V_{RRM}$			0.5	mA
	T _j = 100°C				10	11171
V _F *	I _F = 1A	T _j = 25°C			0.7	V
	I _F = 3A				1	·

^{*} Pulse test: $t_p \le 300 \mu s \ \delta < 2\%$.

DYNAMIC CHARACTERISTICS

Symbol	Test Conditions		Min.	Тур.	Max.	Unit	
С	T _j = 25°C	$V_R = 0$			150		рF
	T _j = 25°C	$V_R = 5V$			40		

Forward current flow in a Schottky rectifier is due to majority carrier conduction. So reverse recovery is not affected by storage charge as in conventional PN junction diodes.

Nevertheless, when the device switches from forward biased condition to reverse blocking state, current is required to charge the depletion capacitance of the diode.

This current depends only of diode capacitance and external circuit impedance. Satisfactory circuit behaviour analysis may be performed assuming that Schottky rectifier consists of an ideal diode in parallel with a variable capacitance equal to the junction capacitance (see fig. 5 page 4/4).

Figure 1. Forward current versus forward voltage at low level (typical values).

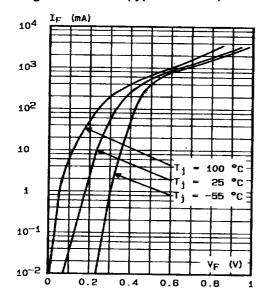


Figure 2. Forward current versus forward voltage at high level (typical values).

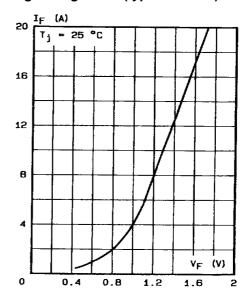


Figure 3. Reverse current versus junction temperature.

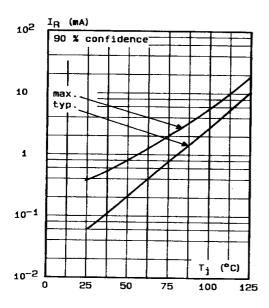


Figure 4. Reverse current versus $V_{\text{RRM}}\,\text{in per cent.}$

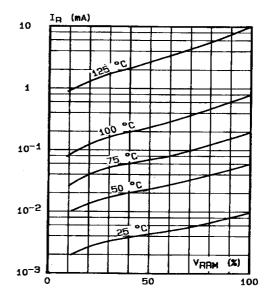


Figure 5. Capacitance C versus reverse applied voltage $V_{\mbox{\scriptsize R}}$ (typical values)

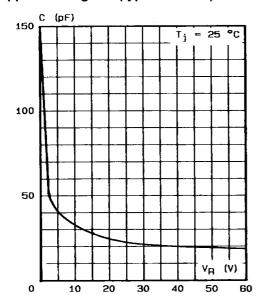


Figure 6. Surge non repetitive forward current for a rectangular pulse with $t \le 10$ ms.

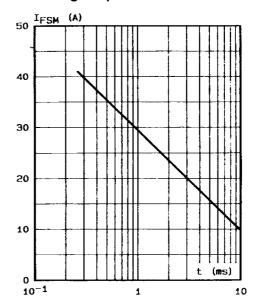
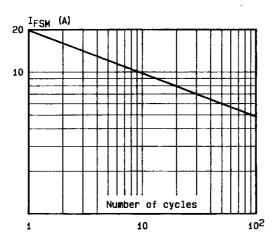
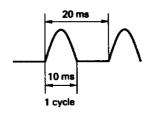


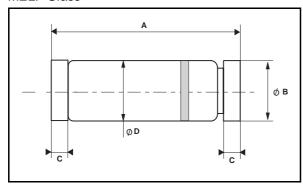
Figure 7. Surge non repetitive forward current versus number of cycles.





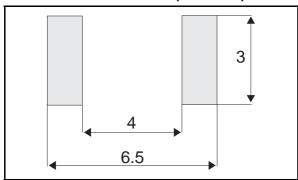
PACKAGE MECHANICAL DATA

MELF Glass



	DIMENSIONS					
REF.	Millimeters			Inches		
	Min.	Тур.	Max.	Min.	Тур.	Max.
Α	4.80		5.20	0.189		0.205
ØB	2.50		2.65	0.098		0.104
С	0.45		0.60	0.018		0.024
Ø D		2.50			0.098	

FOOT PRINT DIMENSIONS (Millimeter)



Marking: ring at cathode end. Weight: 0.15g

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